GTM CORPORATION

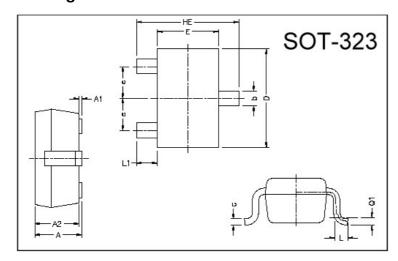
ISSUED DATE :2004/09/24 REVISED DATE :

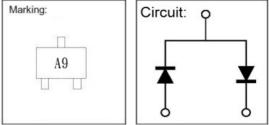
GSN217U

SURFACE MOUNT, SWITCHING DIODE **VOLTAGE 80V, CURRENT 0.1A**

DescriptionThe GSN217U is designed for ultra high speed switching.

Package Dimensions





| REF. | Millimeter | | REF. | Millimeter | |
|------|------------|------|------|------------|------|
| | Min. | Max. | nLI. | Min. | Max. |
| Α | 0.80 | 1.10 | L1 | 0.42 REF. | |
| A1 | 0 | 0.10 | L | 0.15 | 0.35 |
| A2 | 0.80 | 1.00 | b | 0.25 | 0.40 |
| D | 1.80 | 2.20 | С | 0.10 | 0.25 |
| Е | 1.15 | 1.35 | е | 0.65 REF. | |
| HE | 1.80 | 2.40 | Q1 | 0.15 BSC. | |

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

| Parameter | Symbol | Ratings | Unit | |
|--|------------------|------------|------------|--|
| Junction Temperature | Tj | +150 | $^{\circ}$ | |
| Storage Temperature | Tstg | -55 ~ +150 | $^{\circ}$ | |
| Maximum Peak Repetitive Reverse Voltage | V_{RRM} | 80 | V | |
| Maximum RMS Voltage | V_{RMS} | 56 | V | |
| Maximum DC Blocking Voltage | V _{DC} | 80 | V | |
| Peak Forward Surge Current at 1uSec | I _{FSM} | 4.0 | Α | |
| Typical Junction Capacitance between Terminal (Note 1) | CJ | 2.0 | pF | |
| Maximum Average Forward Rectified Current | lo | 0.1 | Α | |
| Total Power Dissipation | PD | 225 | mW | |

Characteristics at $Ta = 25^{\circ}C$

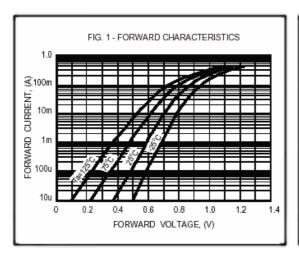
| Characteristics | Symbol | Тур. | Unit | Test Condition |
|---------------------------------------|---------|------|------|----------------|
| Maximum Instantaneous Forward Voltage | V_{F} | 1.20 | ٧ | IF = 100mA |
| Maximum Average Reverse Current | IR | 0.2 | uA | VR = 70V |

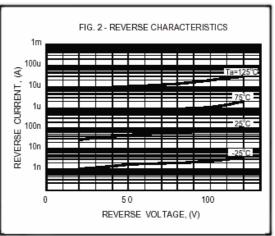
Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 6.0 volt.

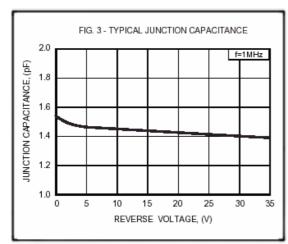
2. ESD sensitive product handling required.

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Characteristics Curve







Important Notice:

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